# BAT85 SMALL SIGNAL SCHOTTKY DIODES

### **FEATURES**

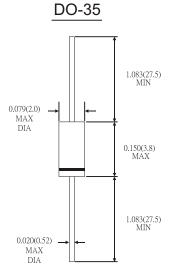
- · For general purpose applications
- These diodes features very low turn-on voltage and fast switching. These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges.
- This diode is also available in the Mini-MELF case with type designation LL85.in the Micro-MELF case with type designation MCL85

## MECHANICAL DATA

· Case: DO-35 glass case

· Polarity: color band denotes cathode end

• Weight : Approx. 0.13 gram



# ABSOLUTE RATINGS(LIMITING VALUES)

Dimensions in inches and (millimeters)

	Symbols	Value	Units
Repetitive Peak Reverse Voltage	VR	30	V
Forward Continuous Current at TA=25°C	l <sub>F</sub>	200 <sup>1)</sup>	mA
Repetitive Peak Forward Current at $t_{D}$ < 1s, $\delta$ < 0.5, TA=25°C	IFМ	300 <sup>1)</sup>	mA
Surge forward current at $t_P < 10 \text{mS}$ , $T_A = 25^{\circ}\text{C}$	IFSM	600 <sup>1)</sup>	mA
Power Dissipation <sup>1)</sup> at TA=65°C	Ptot	200 1)	mW
Junction temperature	TJ	125	ొ
Ambient Operating temperature Range	TA	-65 to+125	°C
Storage Temperature Range	Tstg	-65 to+150	င
1) Valid provided that leads at a distance of 4mm from case are kept of	at ambient temperature		

### **ELECTRICAL CHARACTERISTICS**

	Symbols	Min.	Тур.	Max.	Units
Reverse breakdown voltage Tested with 100µA pulses	V(BR)R	30			٧
Forward voltage Pulse Test $t_{\rm b} < 300 \mu s, \delta < 2\%$ at $t_{\rm e} = 0.1 m A$ , at $t_{\rm e} = 10 m A$ , at $t_{\rm e} = 100 m A$ , at $t_{\rm e} = 100 m A$	VF VF VF VF		0.50	0.24 0.32 0.4 0.8	V V V V
Leakage current VR=25V	lR			2	μΑ
Junction Capacitance at V <sub>R</sub> =1V ,f=1MHz	CJ			10	pF
Reverse recovery time Form I <sub>F</sub> =10mA,I <sub>R</sub> =10mA,I <sub>R</sub> =1mA	trr			5	ns
Thermal resistance junction to ambient Air	Reja			300 <sup>1)</sup>	K/W